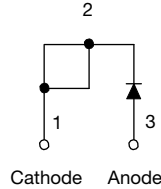




## Fast Soft Recovery Rectifier Diode, 10 A



### FEATURES

- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC®-JESD47
- Fully isolated package ( $V_{INS} = 2500 V_{RMS}$ )
- UL E78996 approved
- Material categorization:  
For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**  
Available

### PRODUCT SUMMARY

Package	TO-220FP
$I_{F(AV)}$	10 A
$V_R$	1000 V, 1200 V
$V_F$ at $I_F$	1.33 V
$I_{FSM}$	140 A
$t_{rr}$	80 ns
$T_J$ max.	150 °C
Diode variation	Single die
Snap factor	0.6

### APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

### DESCRIPTION

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$V_{RRM}$		1000 to 1200	V
$I_{F(AV)}$	Sinusoidal waveform	10	A
$I_{FSM}$		140	
$t_{rr}$	1 A, 100 A/ $\mu$ s	80	ns
$V_F$	10 A, $T_J = 25$ °C	1.33	V
$T_J$		-40 to 150	°C

### VOLTAGE RATINGS

PART NUMBER	$V_{RRM}$ , MAXIMUM PEAK REVERSE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ AT 150 °C mA
VS-10ETF10FPPbF, VS-10ETF10FP-M3	1000	1100	4
VS-10ETF12FPPbF, VS-10ETF12FP-M3	1200	1300	

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 95$ °C, 180° conduction half sine wave	10	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	10 ms sine pulse, rated $V_{RRM}$ applied	115	
		10 ms sine pulse, no voltage reapplied	140	
Maximum $I^2t$ for fusing	$I^2t$	10 ms sine pulse, rated $V_{RRM}$ applied	66	$A^2s$
		10 ms sine pulse, no voltage reapplied	94	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	940	$A^2\sqrt{s}$



<b>ELECTRICAL SPECIFICATIONS</b>					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	10 A, $T_J = 25\text{ }^\circ\text{C}$		1.33	V
Forward slope resistance	$r_t$	$T_J = 150\text{ }^\circ\text{C}$		22.9	m $\Omega$
Threshold voltage	$V_{F(TO)}$			0.96	V
Maximum reverse leakage current	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_{RRM}$	0.1	mA
		$T_J = 150\text{ }^\circ\text{C}$		4	

<b>RECOVERY CHARACTERISTICS</b>					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Reverse recovery time	$t_{rr}$	$I_F$ at 10 Apk 25 A/ $\mu$ s 25 $^\circ\text{C}$	310	ns	
Reverse recovery current	$I_{rr}$		4.7	A	
Reverse recovery charge	$Q_{rr}$		1.05	$\mu\text{C}$	
Snap factor	S		0.6		

<b>THERMAL - MECHANICAL SPECIFICATIONS</b>				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-40 to 150	$^\circ\text{C}$
Maximum thermal resistance junction to case	$R_{thJC}$	DC operation	2.5	$^\circ\text{C/W}$
Maximum thermal resistance junction to ambient	$R_{thJA}$		62	
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth and greased	0.5	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-220 FULL-PAK	10ETF10FP 10ETF12FP	

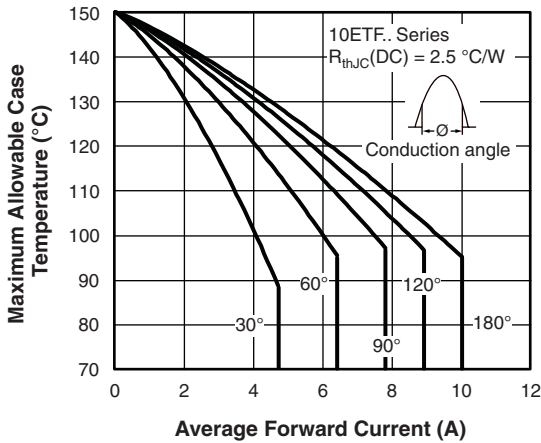


Fig. 1 - Current Rating Characteristics

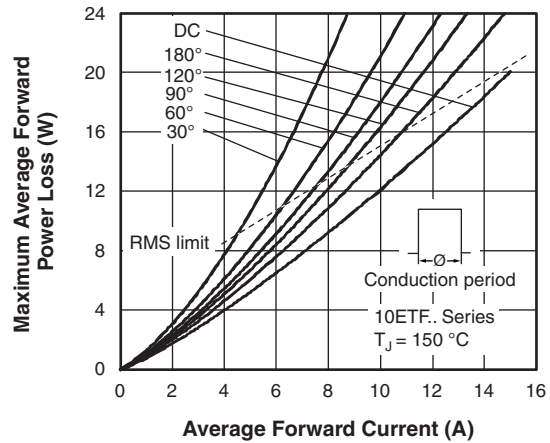


Fig. 4 - Forward Power Loss Characteristics

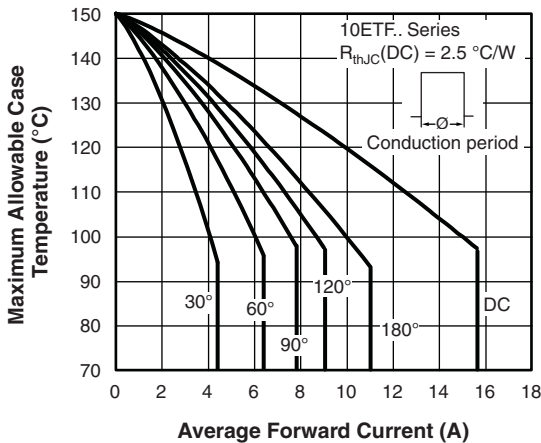


Fig. 2 - Current Rating Characteristics

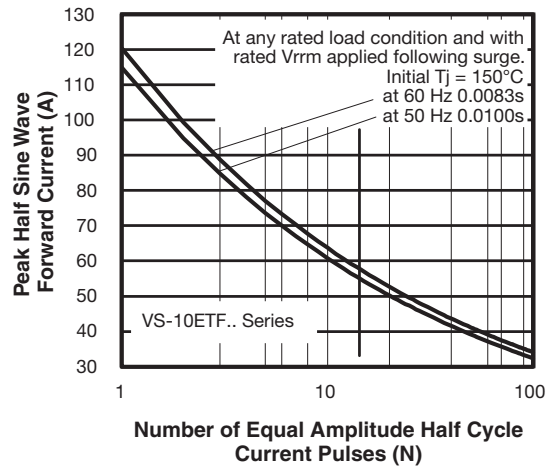


Fig. 5 - Maximum Non-Repetitive Surge Current

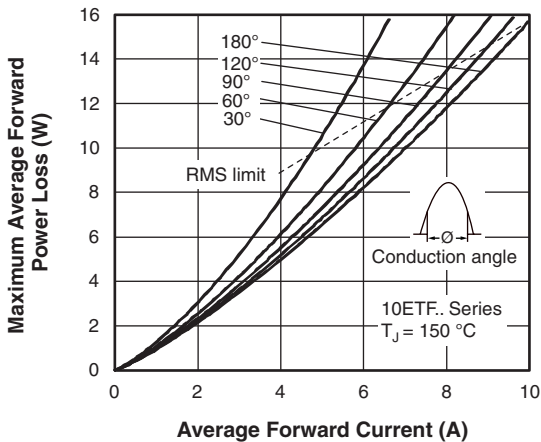


Fig. 3 - Forward Power Loss Characteristics

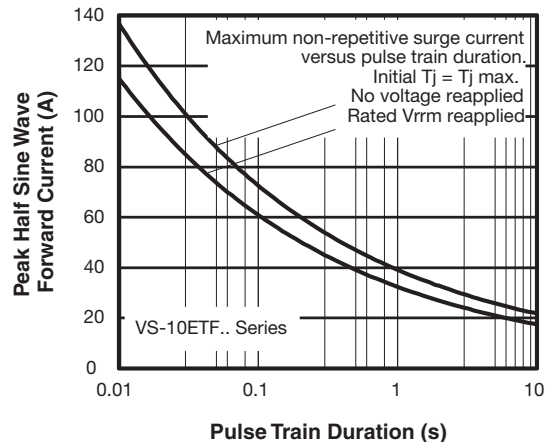


Fig. 6 - Maximum Non-Repetitive Surge Current

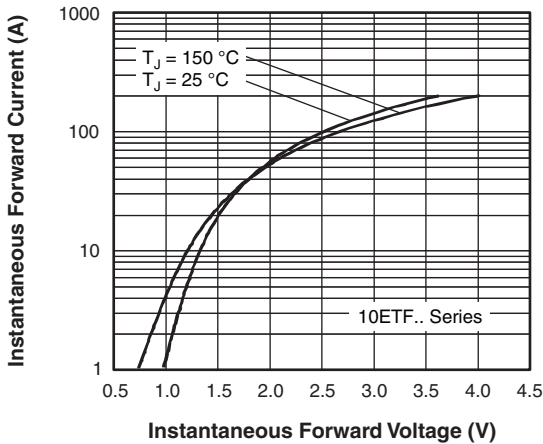


Fig. 7 - Forward Voltage Drop Characteristics

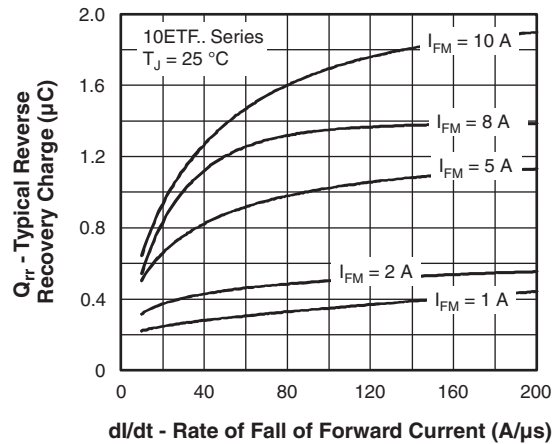


Fig. 10 - Recovery Charge Characteristics,  $T_J = 25\text{ }^\circ\text{C}$

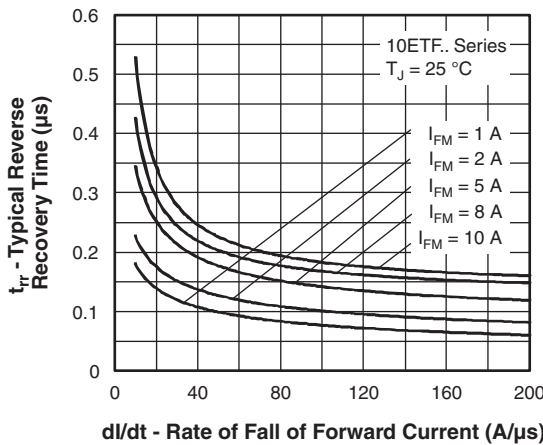


Fig. 8 - Recovery Time Characteristics,  $T_J = 25\text{ }^\circ\text{C}$

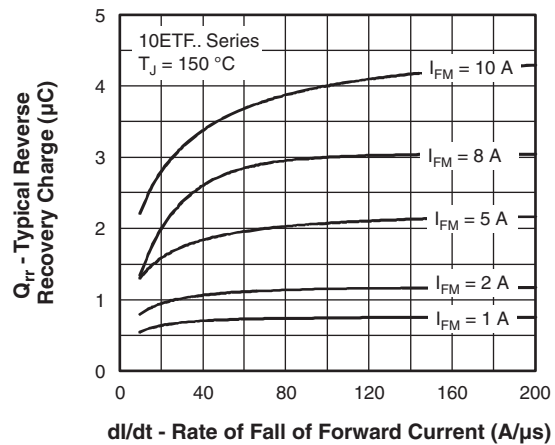


Fig. 11 - Recovery Charge Characteristics,  $T_J = 150\text{ }^\circ\text{C}$

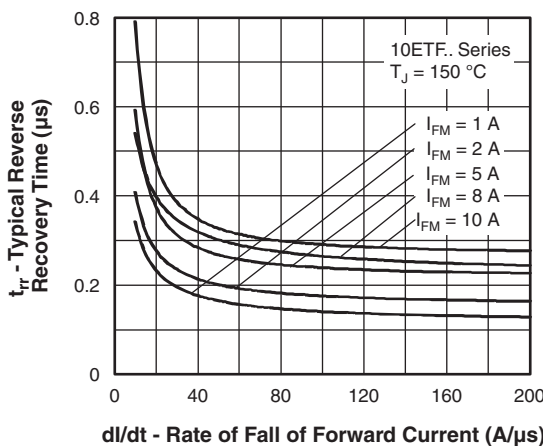


Fig. 9 - Recovery Time Characteristics,  $T_J = 150\text{ }^\circ\text{C}$

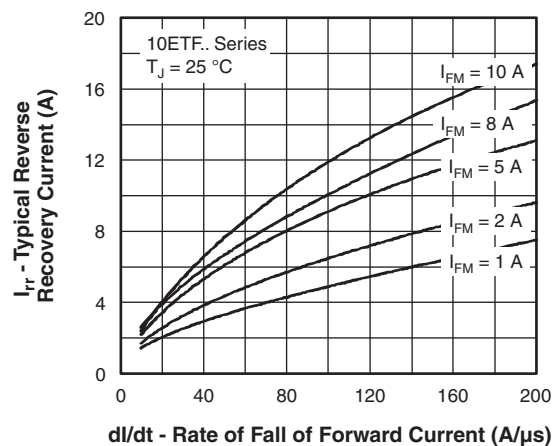


Fig. 12 - Recovery Current Characteristics,  $T_J = 25\text{ }^\circ\text{C}$

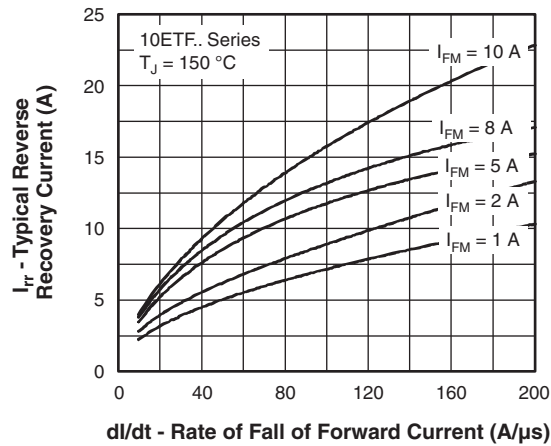


Fig. 13 - Recovery Current Characteristics,  $T_J = 150\text{ }^\circ\text{C}$

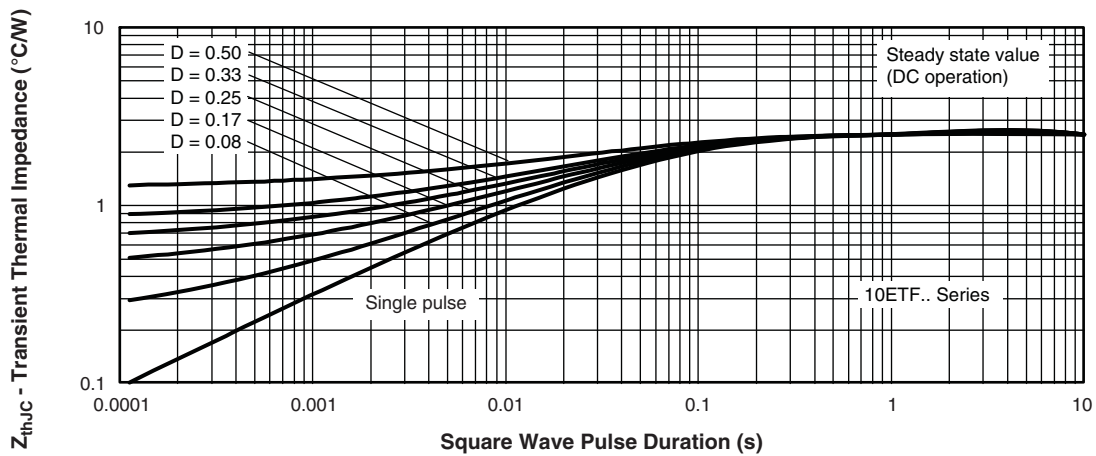
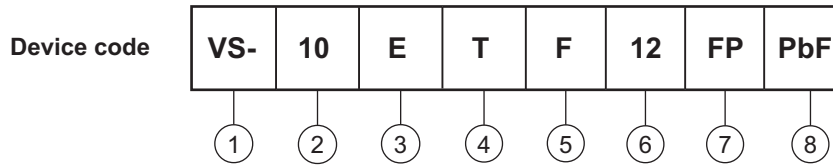


Fig. 14 - Thermal Impedance  $Z_{thJC}$  Characteristics



## ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating (10 = 10 A)
- 3** - Circuit configuration:  
E = Single diode
- 4** - Package:  
T = TO-220
- 5** - Type of silicon:  
F = Fast soft recovery rectifier
- 6** - Voltage code x 100 =  $V_{RRM}$ 

02 = 200 V
04 = 400 V
06 = 600 V
- 7** - FULL-PAK
- 8** - Environmental digit:
  - PbF = Lead (Pb)-free and RoHS compliant
  - -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-10ETF10FPPbF	50	1000	Antistatic plastic tubes
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes
VS-10ETF12FPPbF	50	1000	Antistatic plastic tubes
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95005">www.vishay.com/doc?95005</a>
Part marking information	TO-220 FP PbF <a href="http://www.vishay.com/doc?95009">www.vishay.com/doc?95009</a>
	TO-220 FP -M3 <a href="http://www.vishay.com/doc?95440">www.vishay.com/doc?95440</a>



**DIMENSIONS** in millimeters





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**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

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